## Substitution Effect on the Magnetic Transitions of Fe<sub>2</sub>MnSi

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The Heusler compound Fe<sub>2</sub>MnSi shows intriguing magnetic properties. It exhibits a ferromagnetic transition at  $T_C \sim 220$  K, and, below, another magnetic transition at  $T_R \sim 65$  K, which is supposed to be a ferrimagnetic transition. In the present study we investigate the effects of the substitution of Co and V for Fe and Mn, respectively, on these transitions. They are interesting because the end compound Co<sub>2</sub>MnSi is considered to be a half-metallic ferromagnet and, moreover, the compounds  $(\text{Fe}_{1-y}\text{Co}_y)_2\text{MnSi}$  for larger  $y \gtrsim 0.5$ ) were shown to be candidates for half-metals. Another end compound Fe<sub>2</sub>VSi exhibits an antiferromagnetic transition. These transitions of  $(\text{Fe}_{1-y}\text{Co}_y)_2\text{MnS}$   $(y \leq 0.1)$  and  $\text{Fe}_2\text{Mn}_{1-x}\text{V}_x\text{Si}$   $(x \leq 0.2)$  are investigated with the measurement of magnetization and electrical resistivity. The substitution for either case leads to decreasing  $T_R$  and increasing  $T_C$ . For  $(\text{Fe}_{1-y}\text{Co}_y)_2\text{MnSi}$   $T_R$  appears to vanish at  $y \sim 0.07$ . For  $\text{Fe}_2\text{Mn}_{1-x}\text{V}_x\text{Si}$   $T_R$  appears to vanish in the vicinity of  $x \sim 0.2$ . For  $\text{Fe}_2\text{Mn}_{1.8}\text{V}_{0.2}\text{Si}$  from resistivity measurement in magnetic field  $T_R$  is found not to vanish and to be  $\sim 6$  K at 0 T, and decreases with increasing magnetic field. The destruction of this transition is estimated to occur at  $\sim 6$  T.

<sup>1</sup>Y.Kondo et al., J. Phys.: Conf. Ser. **150**, 042099 (2009).